

1. Record Nr.	UNINA9910350303903321
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Titolo	Deep Ultraviolet LEDs [[electronic resource]] : Understanding the Low External Quantum Efficiency / / by Zi-Hui Zhang, Chunshuang Chu, Kangkai Tian, Yonghui Zhang
Pubbl/distr/stampa	Singapore : , : Springer Singapore : , : Imprint : Springer, , 2019
ISBN	981-13-6179-7
Edizione	[1st ed. 2019.]
Descrizione fisica	1 online resource (IX, 69 p. 40 illus., 39 illus. in color.)
Collana	Nanoscience and Nanotechnology, , 2196-1670
Disciplina	620.11295 620.11297
Soggetti	Optical materials Microwaves Optical and Electronic Materials Microwaves, RF and Optical Engineering Optics, Lasers, Photonics, Optical Devices Signal, Image and Speech Processing
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Nota di contenuto	1.Introduction -- 2.Increase the IQE by improving the crystalline quality for DUV LEDs -- 3.Improve the current spreading for DUV LEDs -- 4. Improve the hole injection to enhance the IQE for DUV LEDs -- 5. Enhance the electron injection efficiency for DUV LEDs -- 6.Screen the polarization induce electric field within the MQWs for DUV LEDs -- 7. Thermal management for DUV LEDs -- 8.The light extraction efficiency for DUV LEDs -- 9. Conclusions and outlook.
Sommario/riassunto	This book highlights the origin of low external quantum efficiency for deep ultraviolet light-emitting diodes (DUV LEDs). In addition, it puts forward solutions for increasing the internal quantum efficiency and the light extraction efficiency of DUV LEDs. The book chiefly concentrates on approaches that can be used to improve the crystalline quality, increase carrier injection, reduce the polarization-induced electric field within multiple quantum wells, suppress the TM polarization emission, and enhance the light escape from the semiconductor layer. It also demonstrates insightful device physics for DUV LEDs, which will greatly

benefit the optoelectronic community.
